

Title (en)
IC MODULE, METHOD OF FABRICATING THE SAME AND IC CARD PROVIDED WITH IC MODULE

Title (de)
IC-MODUL, SEIN HERSTELLUNGSVERFAHREN UND IC-KARTE DAMIT VERSEHEN

Title (fr)
MODULE A CIRCUIT INTEGRE, PROCEDE DE FABRICATION DUDIT MODULE ET CARTE A CIRCUIT INTEGRE DOTE E DUDIT MODULE

Publication
EP 0923047 A4 20010829 (EN)

Application
EP 98931083 A 19980713

Priority
• JP 9803141 W 19980713
• JP 19384297 A 19970718

Abstract (en)
[origin: EP0923047A1] In the method of manufacturing an IC module (1) including a resin packaging process using upper and lower dies (5) for forming a cavity (50) while the dies are clamped, the resin packaging process is carried out by introducing a melted resin while a substrata (2) on which an IC chip (3) is placed and a coil (20A) which has a doughnut shape when observed from above and is flattened as a whole are housed in the cavity (50). When a substrate (2) on which an antenna coil (20) is patterned is to be packaged with a resin, the resin packaging process is carried out by forming a spacer (28) having an equal and almost equal height to the height of the cavity (50) on the substrate (2), housing it in the cavity (50), and introducing a melted resin. Instead of forming the spacer (28) on the substrate (2), a substrate (2) housed in a cavity (50) may be sucked. The manufacturing method can provide good protection of an IC chip and an antenna coil. <IMAGE>

IPC 1-7
G06K 19/077; **B29C 45/14**

IPC 8 full level
B42D 15/10 (2006.01); **B29C 45/14** (2006.01); **G06K 19/07** (2006.01); **G06K 19/077** (2006.01); **H01Q 7/00** (2006.01); **B29C 45/00** (2006.01)

CPC (source: EP KR US)
B29C 45/14647 (2013.01 - EP US); **G06K 19/067** (2013.01 - KR); **G06K 19/07724** (2013.01 - EP US); **G06K 19/07745** (2013.01 - EP US); **G06K 19/07747** (2013.01 - EP US); **G06K 19/07749** (2013.01 - EP US); **B29C 45/0046** (2013.01 - EP US); **B29L 2031/3456** (2013.01 - EP US); **H01L 2224/16** (2013.01 - EP US); **H01L 2924/01057** (2013.01 - EP US); **H01L 2924/01078** (2013.01 - EP US); **H01L 2924/01079** (2013.01 - EP US)

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Designated contracting state (EPC)
DE FR GB NL

DOCDB simple family (publication)
EP 0923047 A1 19990616; **EP 0923047 A4 20010829**; **EP 0923047 B1 20071031**; AU 2003246072 A1 20031009; AU 2003246072 B2 20050908; AU 761860 B2 20030612; AU 8129898 A 19990210; CA 2265918 A1 19990128; CN 1167039 C 20040915; CN 1234886 A 19991110; DE 69838638 D1 20071213; DE 69838638 T2 20080828; JP H1134553 A 19990209; KR 100300253 B1 20010922; KR 20000068556 A 20001125; US 6308894 B1 20011030; WO 9904365 A1 19990128

DOCDB simple family (application)
EP 98931083 A 19980713; AU 2003246072 A 20030912; AU 8129898 A 19980713; CA 2265918 A 19980713; CN 98800978 A 19980713; DE 69838638 T 19980713; JP 19384297 A 19970718; JP 9803141 W 19980713; KR 19997002152 A 19990313; US 14781599 A 19990312